Description:

– is the series of high-power multimode laser diode with emission wavelength in spectral range of 1.24÷1.28 μm and CW output power of 800 mW produced on the base of InGaAsP/InP index-guided heterostructures. The laser diode is performed in standard HHL package with built-in monitor photodiode, thermistor, termocooler and have wide operating temperature range, high output power stability and more than 10^4 hours of lifetime.



- is the best light source for medical applications, for driving of technology procedures, scientific and research works, etc.

Absolute maximum ratings:

Laser diode	
CW output power (mW)	900
Operating current (mA)	3.3
Monitor photodiode	
Reverse voltage (V)	6.0
PD current (mA)	1.0
Thermistor	
Operating current (mA)	0.1
Voltage drop (V)	10

Thermocooler	
Forward current (mA)	2.3
Forward voltage (V)	10.4
Environment	
Operating temperature range (°C)	-20+40
Storage temperature range (°C)	-40+70
Assembly	
Pin soldering temperature (°C)	200
Pin soldering time (sec)	3.0

Optical and electrical characteristics (T=25°C):

Characteristics	Symbol	Min	Тур	Max	Units
Laser diode					
CW output power	P_{OUT}		800		mW
Emitting area	W x H		100 x 1		μm
Wavelength	λ	1240	1260	1280	nm
Threshold current	I_{TH}			700	mA
Operating current	I_{F}			2.8	A
Operating voltage	U_{F}			2.0	V
Beam divergence	$\Theta_{\text{II}} \times \Theta_{\perp}$		10 x 50		deg
Spectral width (FWHM)	Δλ		5	7	nm
Mode structure			MM		
Monitor photodiode					
Monitor PD current	I_{PD}		>20		μΑ
Sensitivity	S		>0.2		μA/mW
Reverse voltage	$U_{\mathtt{PD}}$		5.0 ± 0.5		V
Thermocooler					
Operating current	I_{OP}			1.5	A
Operating voltage	U_{OP}		6	7	V
Thermistor					
Resistance	R		20		kΩ

Pin	Function	
1	"-" thermocooler	
2	case	
3	LD anode (+)	
4	thermistor	
5	thermistor	
6	LD cathode (-)	
7	PD anode	
8	PD cathode	
9	"+" thermocooler	

